Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

55.880 millimeters

Terminal Length:

5.080 millimeters

End Application:

Dcn'onlye/ifscm66891

Mounting Facility Quantity:

2

Mounting Method:

Terminal

Terminal Circle Diameter:

2.260 millimeters

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 reverse voltage, peak

Current Rating Per Characteristic:

1.00 amperes forward current, average preset

Power Rating Per Characteristic:

500.0 microwatts small-signal input power, common-emitter outside diameter

Capacitance Rating In Picofarads:

6.0

Maximum Operating Tempurature Per Measurement Point:

-65.0 degrees celsius case and 200.0 degrees celsius case

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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